

Problem Set 6

□ Section 6.4 (High-Frequency Response - general considerations):

- **Problem 1:** 6.54 in the textbook.

□ Sections 6.6 and 6.8 (High-Frequency Response of Amplifiers)

- **Problem 2:** 6.99 in the textbook.

- **Problem 3:**

For the amplifiers in Figures 1 and 2, derive an expression for:

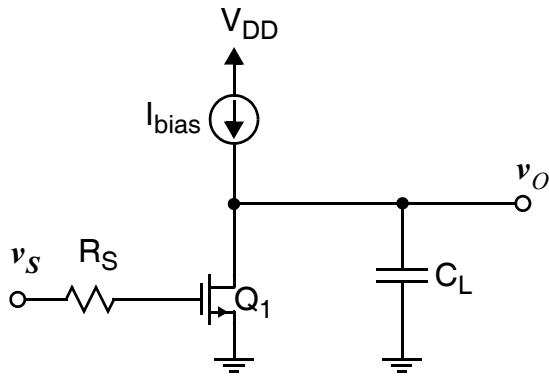
- i) the midband voltage gain $A_M = v_o/v_s$;
- ii) the 3dB-frequency ω_H , assuming a dominant pole exist.

Hint: Follow the following steps to find ω_H :

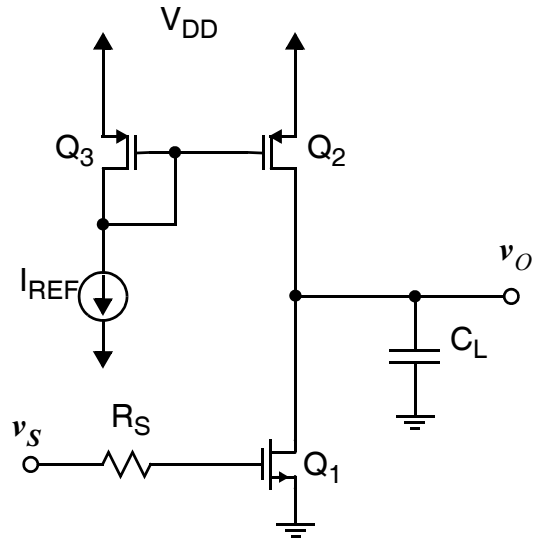
- 1) apply Miller's theorem;
- 2) find the open-circuit time constants (poles) associated with each node;
- 3) find ω_H based on the open-circuit time-constant approximation, assuming a dominant pole exists.

Assume:

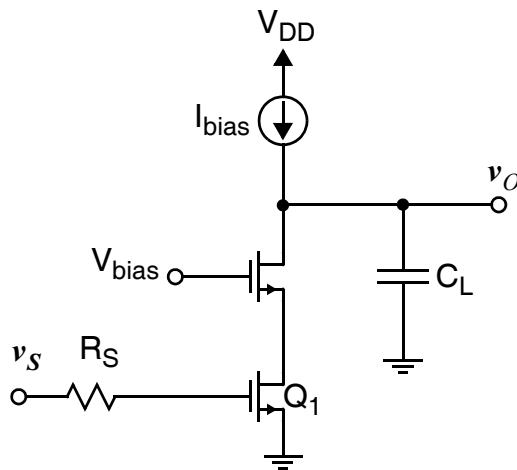
- Biasing:
 - each current source has an output resistance of R_L .
 - the dc-bias voltage level at the output is stabilized by negative feedback, with all BJTs and MOSFETs biased in the active and saturation modes, respectively.
- For the MOS amplifiers in Figure 1:
 - the body effect is negligible.
 - the substrate (Body) terminal of the NMOS transistors is connected to GND .
 - the substrate (Body) terminal of the PMOS transistors is connected to V_{DD} .
- For the BJT amplifiers in Figure 2:
 - neglect the small-signal base resistance r_x .



(a) Common-Source Amplifier

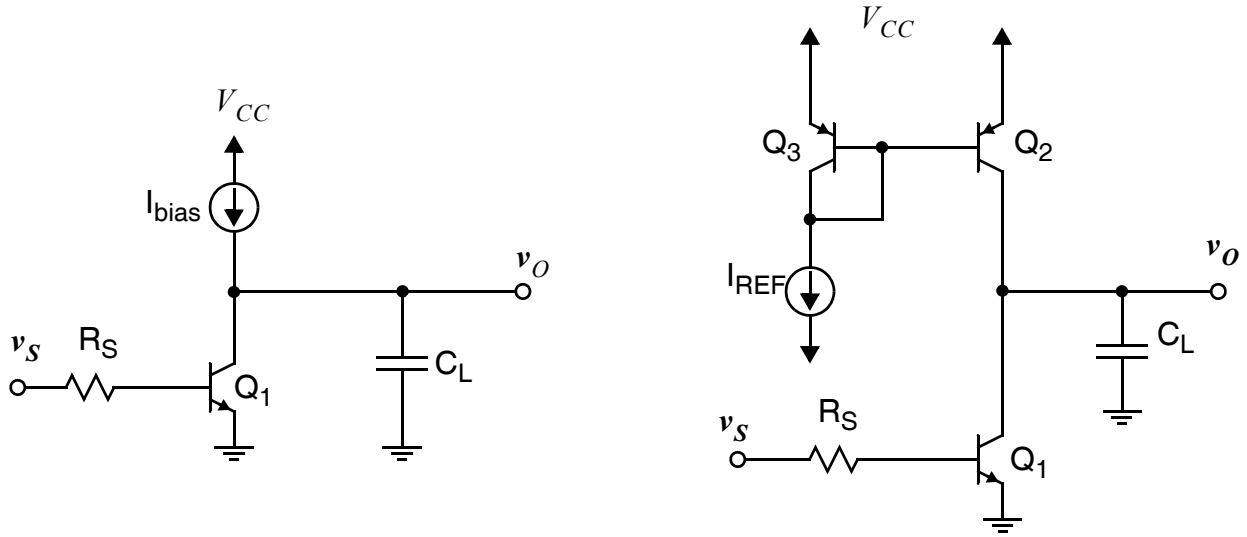


(b) Common-Source Amplifier with Active Load
(assume the gate of Q₂ is at signal GND)



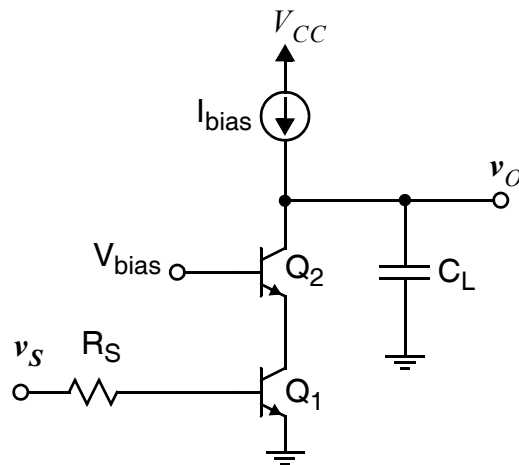
(c) MOS Cascode Amplifier

Figure 1 MOS amplifiers.



(a) Common-Emitter Amplifier

(b) Common-Emitter Amplifier with Active Load
(assume the base of Q_2 is at signal GND)



(c) BJT Cascode Amplifier

Figure 2 BJT amplifiers.

□ Sections 6.12 (Advanced Current Mirrors) and 7.7 (Multistage Amplifiers)

• **Problem 4:**

For the 2-stage differential amplifier in Figure 3 (where the bias-voltage level at the output is assumed to be stabilized by feedback to about 0 V), find:

- i) the small-signal voltage gain $\frac{v_{out}}{v_{in}}$.
- ii) the input common-mode range of the amplifier, assuming $|V_{BEon}| = 0.7V$ and $|V_{CEsat}| = 0.3V$ for every transistor, and $\pm 3.3-V$ power supplies.

Assume that the resistance looking into the collector of Q9 (i.e. R_{o9}) is approximately equal to the output resistance of the BJT (i.e. r_{o9}).

All pnp transistors have $\beta = 50$ and $|V_A| = 80V$, and all npn transistors have $\beta = 250$ and $|V_A| = 125V$. When calculating the dc currents, you can ignore the base current of every transistor.

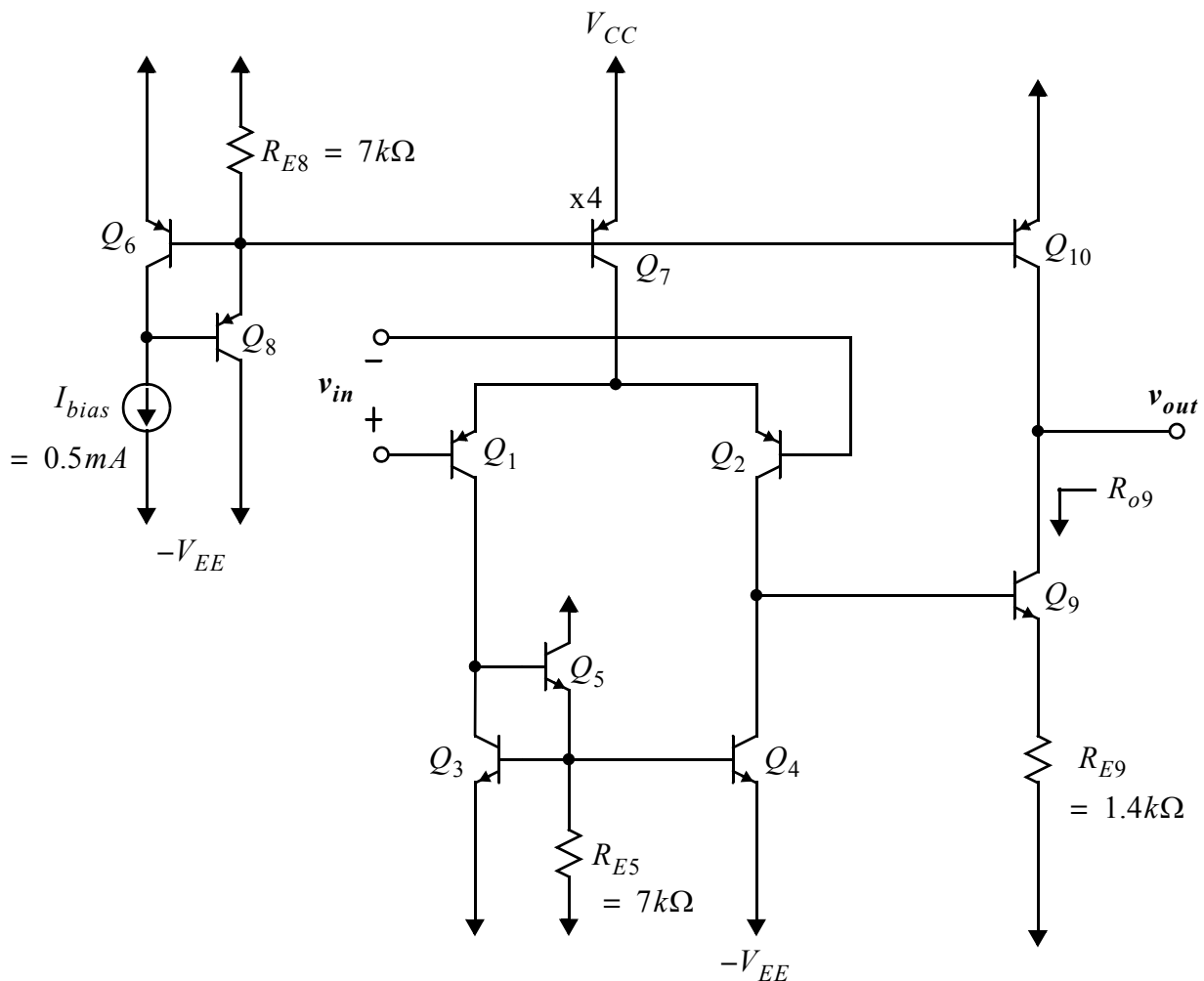


Figure 3 A BJT realization of a 2-stage differential amplifier.